

WHAT IS CLAIMED IS:

1. A light-emitting device comprising:
a light-emitting layer; and
an electrode layer,
wherein film thickness of the electrode layer is set so that light extracted from the light-emitting device out of light emitted in the light-emitting layer has a predetermined chromaticity value.
2. A light-emitting device comprising:
a substrate;
a light-emitting layer disposed above the substrate;
an electrode layer disposed above the light-emitting layer; and
a material layer disposed above the electrode layer to cover the light-emitting layer,
wherein film thickness is set so that light extracted through at least the material layer out of light emitted in the light-emitting layer has a predetermined chromaticity value.
3. A light-emitting device comprising:
a substrate;
a light-emitting layer disposed above the substrate; and
an electrode layer disposed above the light-emitting layer,
wherein film thickness is set so that light extracted through at least the substrate out of light emitted in the light-emitting layer has a predetermined chromaticity value.
4. An organic EL device comprising:
a substrate;
an organic EL layer disposed above the substrate;
an electrode layer disposed above the organic EL layer; and
a material layer disposed above the electrode layer to cover the organic EL layer,
wherein film thicknesses are set so that light extracted through at least the material layers out of light emitted in the organic EL layers has a predetermined chromaticity value.
5. An organic EL device comprising:
a substrate;

an organic EL layer disposed above the substrate; and
 an electrode layer disposed above the organic EL layer,
 wherein film thickness is set so that light extracted through at least the
 substrate out of light emitted in the organic EL layer has a predetermined chromaticity value.

6. The light-emitting device according to Claim 1,
 wherein the light-emitting layer comprises three types of light-emitting layer
 corresponding to the three colors red, green, and blue, and
 wherein the film thicknesses of the electrode layers are individually set
 corresponding to the regions on which light from the three types of light-emitting layers is
 incident.
7. The light-emitting device according to Claim 1,
 wherein the electrode layer comprise a plurality of laminated layers, and
 wherein the film thickness of at least one of the plurality of layers is set.
8. The light-emitting device according to Claim 7,
 wherein the plurality of layers comprise transparent layers for transmitting the
 light from the light-emitting layers and reflective layers for reflecting the light, and
 wherein the film thicknesses of the transparent layers are set.
9. An electronic apparatus comprising the light-emitting device according to
 Claim 1.
10. A method of manufacturing a light-emitting device, comprising the steps of:
 disposing a light-emitting layer above a substrate;
 disposing an electrode layer above the light-emitting layer; and
 disposing a material layer above the electrode layer to cover the light-emitting
 layer,
 wherein film thickness of the electrode layer is set so that light extracted
 through at least the material layer out of light emitted in the light-emitting layer has a
 predetermined chromaticity value.
11. A method of manufacturing a light-emitting device, comprising the steps of:
 disposing a light-emitting layer above a substrate; and
 disposing an electrode layer above the light-emitting layer,
 wherein film thickness of the electrode layer is set so that light extracted
 through at least the substrate out of light emitted in the light-emitting layer has a
 predetermined chromaticity value.

12. The method of manufacturing a light-emitting device according to Claim 10,
wherein the light-emitting layer comprises three types of light-emitting layers
corresponding to the three colors red, green, and blue, and
wherein the film thicknesses of the electrode layers are individually set
corresponding to the regions on which light from the three types of light-emitting layers is
incident.
13. The method of manufacturing a light-emitting device according to Claim 12,
wherein the three types of light-emitting layers are disposed by using a mask
vapor deposition method.